

## GaAs MMIC Absorptive SP3T Switch Chip, DC- 12 GHz

### Performance characteristics

- Frequency range: DC - 12 GHz
- Insertion loss : 1.8 dB
- Isolation: 48 dB
- On-state VSWR : 1.4
- 50Ohm input/output
- QFN4X4mm

### Product Introduction

GSW-00123T is a GaAs MMIC absorptive single-pole triple-throw switch chip with 50Ω matching at the input/output ends, a frequency range covering DC ~ 12 GHz , and 0V/-5V power supply. The switching speed is 20ns. The amplifier adopts a 4X4mm surface-mount leadless ceramic tube shell to achieve airtight packaging. The surface of the pin pad is gold-plated and is suitable for reflow soldering installation.

Use restriction parameter <sup>1</sup>	
Control voltage range	-8V ~ +0.5V
Maximum input power	+30dBm
Operating temperature	-55 ~ +85°C
Storage temperature	-65 ~ +150°C

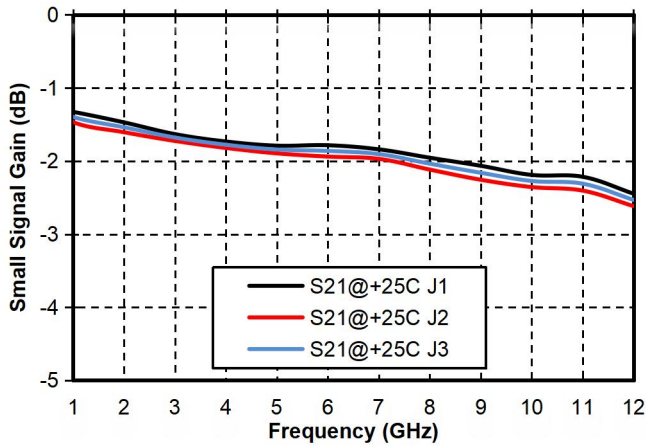
【1】 Exceeding any of these maximum limits may cause permanent damage.

Electrical Parameters ( TA = +25°C)				
Index	Minimum	Typical Value	Maximum	Unit
Frequency Range	DC-12			GHz
Insertion loss	-	1.8	-	dB
Isolation	-	48	-	dB
Input return loss	-	19	-	dB
Output return loss	-	21	-	dB
P-1dB	-	23	-	dBm
Switching speed	-	20	-	ns

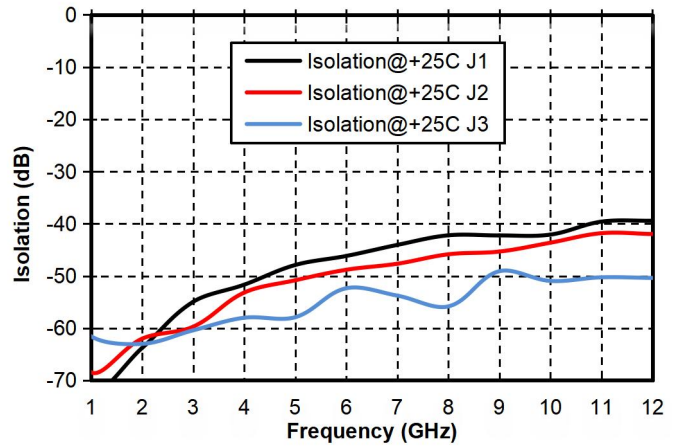
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Main index test curve

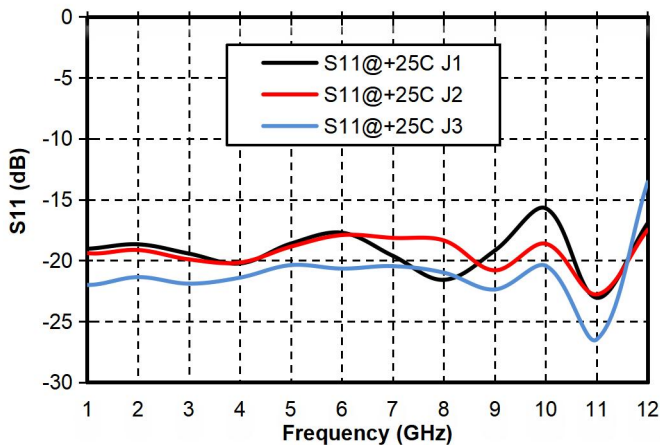
Insertion Loss vs. Operating Frequency



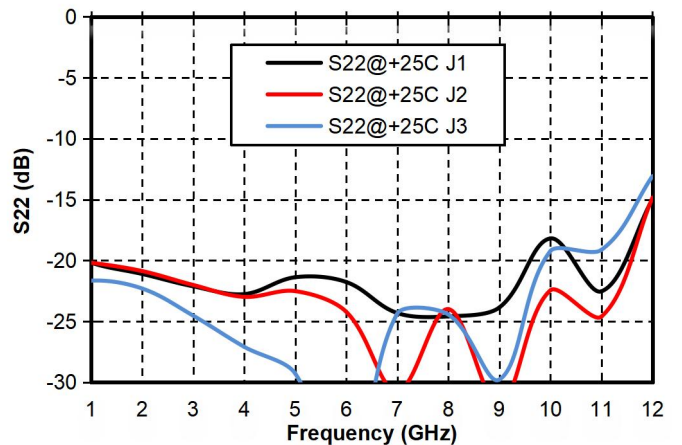
Isolation vs. Operating Frequency



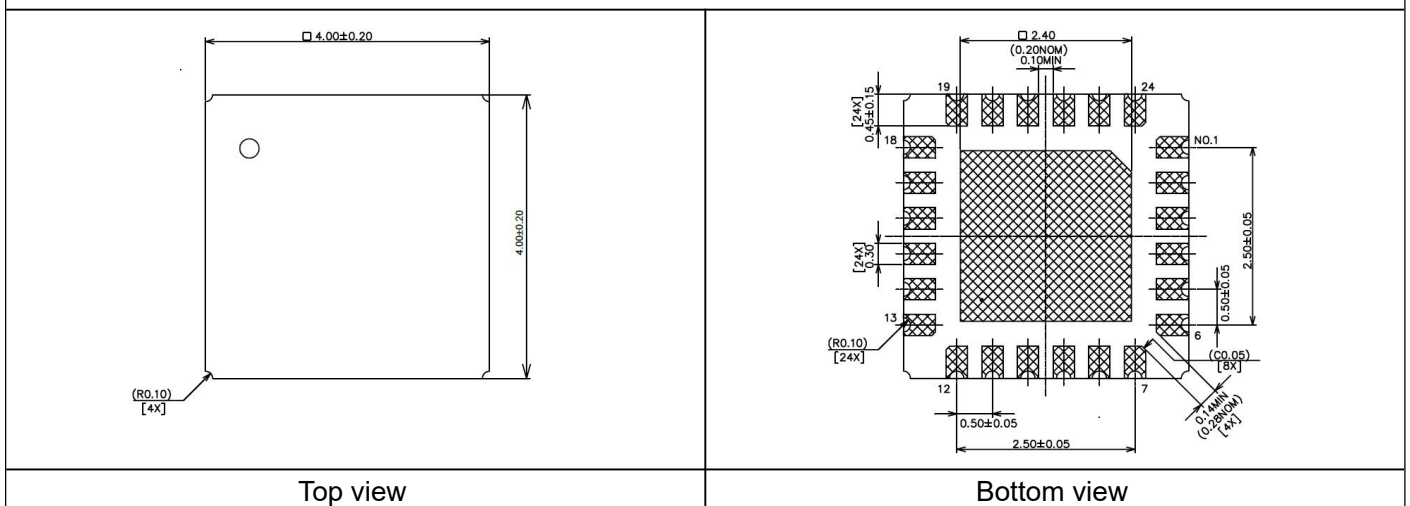
Input Wave Loss vs. Operating Frequency



Output Return Loss vs. Operating Frequency

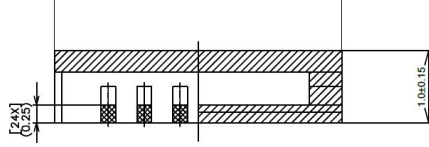


### Appearance structure



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Appearance structure



Side View

All units in the figures are millimeters.

### Truth table

1A	1B	2A	2B	3A	3B	IN-OUT1	IN-OUT2	IN-OUT3
0V	-5V	-5V	0V	-5V	0V	Conductivity	closure	closure
-5V	0V	0V	-5V	-5V	0V	closure	Conductivity	closure
-5V	0V	-5V	0V	0V	-5V	closure	closure	Conductivity

### Pin Definition

Pin number	Function Symbol	Functional Description
3	RFIN	Signal input terminal, external DC blocking capacitor is required
11, 16, 20	RF OUT1/2/3	Signal output terminal, external DC blocking capacitor is required
2, 4, 10, 12, 15, 17, 19, 21	GND	The bottom of the chip needs to be well grounded to RF and DC
1, 6-8, 23, 24	Voltage Control	On/off control
other	NC	The pin is left floating and can be grounded

### Application Circuit

